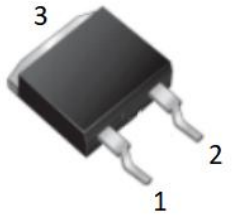
Technical Data
Data Sheet N2772, REV.-

RoHS

S4D02120G0
1200V SIC POWER SCHOTTKY RECTIFIER

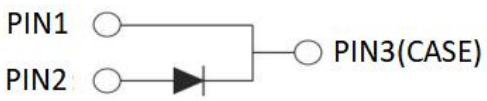


D²PAK(TO-263 HV)

Description

The S4D02120G0 is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S4D02120G0 is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



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Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	1200	V
Average Rectified Forward Current	$I_{F\ (AV)1}$	T_C =25°C	8	A
	$I_{F\ (AV)2}$	T_C =160°C	2	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM1}	10ms, Half Sine pulse, T_C =25°C	27	A
	I_{FSM2}	10ms, Half Sine pulse, T_C =110°C	25	A
Repetitive Peak Forward Surge Current	I_{FRM1}	10ms, Half Sine pulse , T_C =25°C	16	A
	I_{FRM2}	10ms, Half Sine pulse , T_C =110°C	14	A
Power Dissipation	P_{tot1}	T_C =25℃	56	W
	P_{tot2}	T_C =110℃	24	W

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Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 2A, Pulse, T_J = 25 °C	1.4	1.8	V
	V_{F2}	@ 2A, Pulse, T_J = 175 °C	2.0	2.5	V
Reverse Current*	I_{R1}	@V_R = rated V_R, T_J = 25 °C	1	10	uA
	I_{R2}	@V_R = rated V_R, T_J = 175 °C	2	40	uA
Junction Capacitance	C_T	VR=0V, f=1MHz, T_J=25℃,	160	-	pF
		VR=4V, f=1MHz, T_J=25℃,	87	-	
Reverse Recovery Charge	Q_c	V_R = 800 V, T_J =25°C	12.33	-	nC
Capacitance Stored Energy	E_C	V_R = 800 V, T_J =25°C	6.33	-	μJ

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	S4D02120G0	Units
Junction Temperature	T_J	-	-55 to +175	°C
Storage Temperature	T_{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation,Tj=25℃	2.7	°C/W

Ordering Information

Device	Package	Shipping
S4D02120G0	D2PAK(TO-263-2)	800pcs / Reel
S4D02120G0TR	D2PAK(TO-263-2)	800pcs / Reel

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Ratings and Characteristics Curves

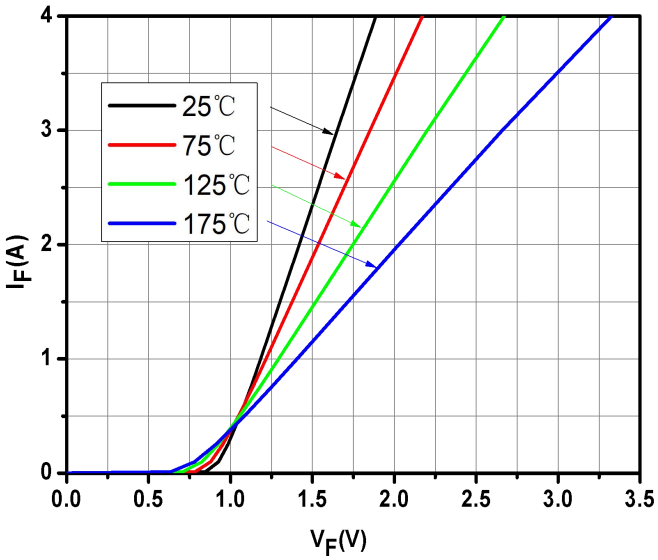

Fig.1-Typical Forward Voltage Characteristics

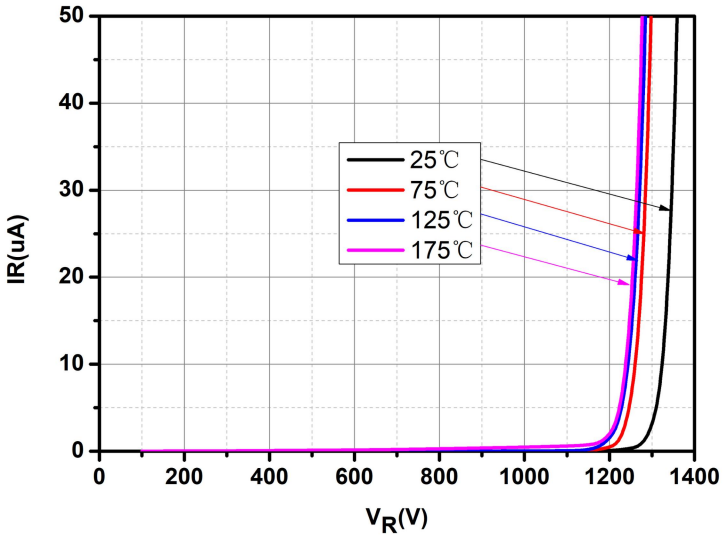

Fig.2-Typical Reverse Characteristics

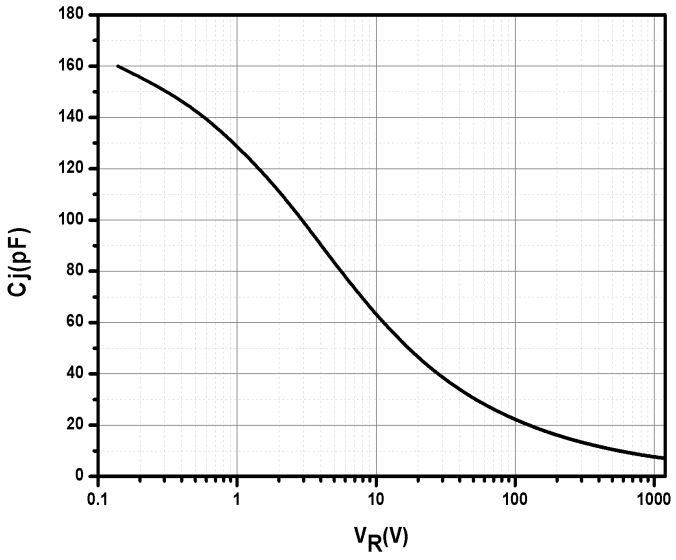

Fig.3-Capacitance vs. Reverse Voltage

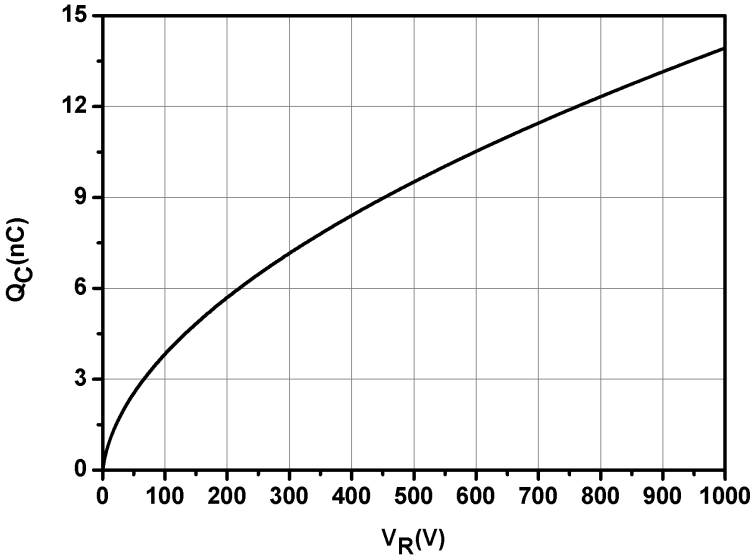

Fig.4-Total Capacitance Charge vs. Reverse Voltage

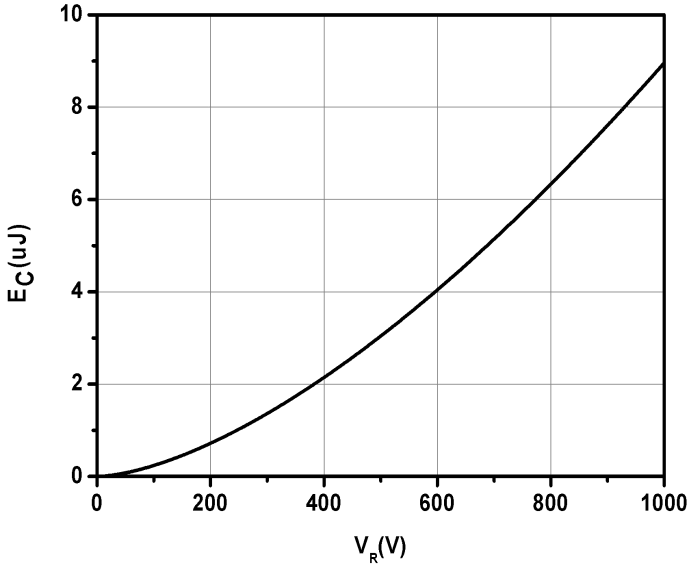

Fig.5-Capacitance Stored Energy

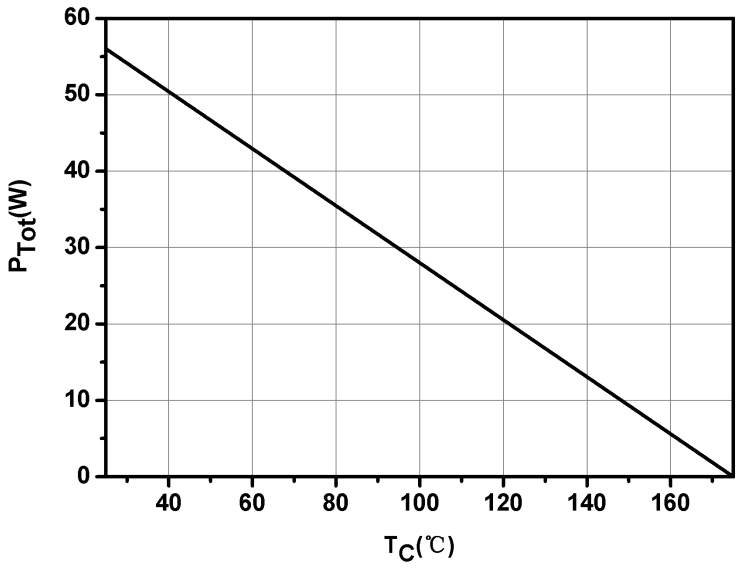

Fig.6-Power Derating

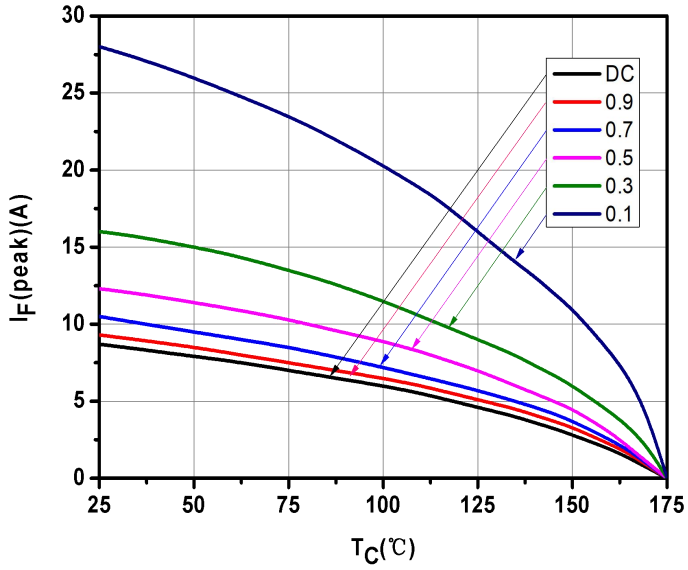

Fig.7-Current Derating

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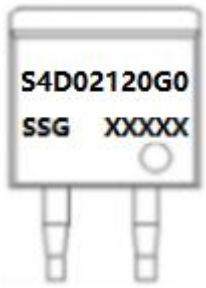
Marking Diagram

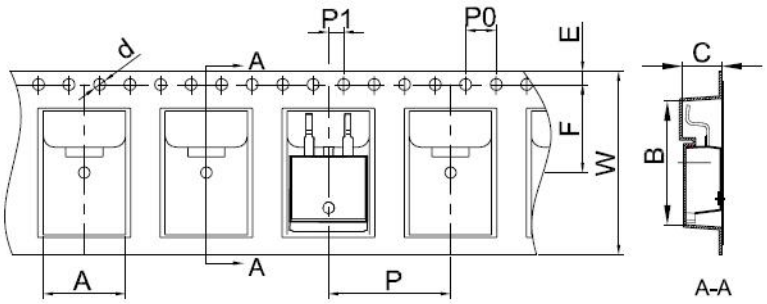


Where XXXXX is YYWWL

S4D = Device Type
G0 = Package type
02 = Forward Current (2A)
120 = Reverse Voltage (1200V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Carrier Tape & Reel Specification D2PAK(TO-263 HV)



SYMBOL	Millimeters	
	Min.	Max.
A	10.70	10.90
B	16.03	16.23
C	5.11	5.31
d	1.45	1.65
E	1.65	1.85
F	11.40	11.60
P0	3.90	4.10
P	15.90	16.10
P1	1.90	2.10
W	23.90	24.30

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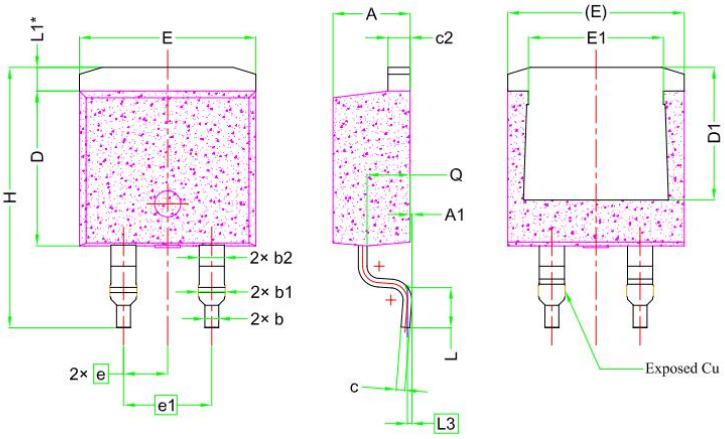
Mechanical Dimensions D²PAK(TO-263 HV)



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.24	4.44	4.64
A1	0.00	0.10	0.25
b	0.70	0.80	0.90
b1	1.20	1.55	1.75
b2	1.20	1.45	1.70
c	0.40	0.50	0.60
c2	1.15	1.27	1.40
D	8.82	8.92	9.02
D1	6.86	7.65	-
E	9.96	10.16	10.36
E1	6.89	7.77	7.89
e	2.54 BSC		
e1	5.08 BSC		
H	14.61	15.00	15.88
L	1.78	2.32	2.79
L1	1.39 REF		
L3	0.25 BSC		
Q	2.30	2.48	2.70

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